Product specification of Solar Space P-type crystalline silicon solar cells --Product : P15675-5BF106-JK

1. Scope

This specification is applicable to Solar Space p-type(boron doping) muti-crystalline silicon solar cells, and specified the aforesaid solar cells characteristics and application conditions.

2. Normative references

Document number	Title			
IEC 60904-1 Ed.2.0	Photovoltaic devices – Part 1:measurements of photovoltaic			
	current-voltage characteristics			
IEC 60904-3 Ed.2.0	Photovoltaic devices – Part 3: Measurement principles for			
	terrestrial photovoltaic (PV) solar devices with reference			
	spectral irradiance data			
IEC 60904-7 Ed.3.0	Photovoltaic devices – Part 7: Computation of spectral			
	mismatch error introduced in the testing of a photovoltaic			
	device			
IEC 61215 Ed.2.0	Crystalline silicon terrestrial photovoltaic (PV) modules –			
	Design qualification and type approval			

3. Specification

3.1 Cell structure

Cell Structure see Table 1.

Tab 1 Cell Structure

Substrate material	P-type multi-crystalline silicon wafer			
Cell thickness	200µm±20µm, 180µm±20µm			
Dimension	156.75±0.25mm			
Diagonal	220.2mm±0.5mm			
Front(-)	Acid textured surface, blue silicon nitride AR coating			
	Silver busbars for the front electrodes			
Back(+)	Aluminum back-surface field			
	Silver soldering pads for the backside electrodes			

Front silver pastes : Samsung Series 8730x, Heraeus SOL964x. Aluminum pastes : Rutech RX8252x, Hoyi Series HY-16xx. Back silver pastes : Sun technology Series U-8820x, Rutech RX61041x

3.2 Printing pattern and Electric characteristics

Efficiency Code	Unit	1900	1890	1880	1870	1860	1850	1840
Voc	V	0.639	0.637	0.636	0.634	0.633	0.632	0.631
lsc	А	8.994	8.966	8.937	8.916	8.899	8.868	8.810
Vmp	V	0.548	0.546	0.544	0.543	0.541	0.540	0.540
Imp	А	8.490	8.462	8.438	8.419	8.405	8.377	8.312
Pmax	W	4.653	4.621	4.593	4.569	4.547	4.523	4.491
Efficiency	%	19.00	18.90	18.80	18.70	18.60	18.50	18.40

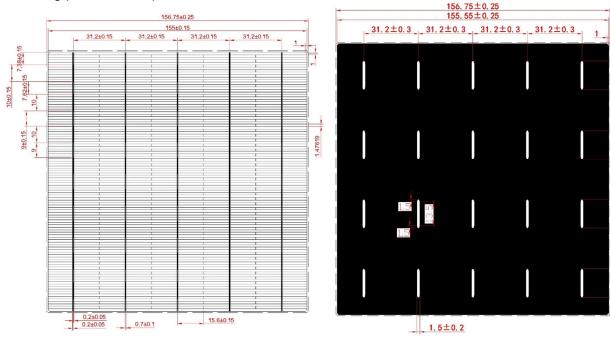
The electrical data apply to standard test conditions(STC):

Irradiance of $1000W/m^2$, with spectrum AM 1.5 and a cell temperature of 25 °C.

The above data are average figures presently measured. Reference data are calibrated by Fraunhofer ISE.

Just for reference.

Printing patterns and parameters



Temperature Coefficient (Typical data for reference)

Pmax.Temp.Coef	-(0.39±0.02) %/k
Voc.Temp.Coef	-(0.32±0.03) %/k
lsc.Temp.Coef	+(0.05±0.015) %/k

3.3 Light induced degradation test

Using Xenon lamp (Irradiance of 1000W/ m^2 ,with spectrum AM 1.5) to irradiate test cells, after a

total irradiation of 5 kwh·m⁻², the degradation of maximum output power of cells is $\leq 2\%$.

3.4 CTM

Lower cell to module(CTM) power loss : <1%.

16.5+0.

23.3

23.

23.

16.5+0.

3.5 Anti-PID

Potential Induced Degradation(-1000V, 96Hrs):<5%

4. Labeling, Packaging, Storage

4.1 Labeling

Internal box unit and outside package have to be labeled with the following data: cell type, cell class, efficiency, power, amount, color class, barcode and other related information.

Sign including breakable, upward, stack number limit, avoid wet and Solar space logo are printed on the outside package.

4.2 Packaging

Solar cells are closely packed in cardboard box and heat shrink , air cushion is used around the box unit, to be suitable for long-distance delivery.



4.3 Storage

After packaging, cells should be stored indoors in the conditions of good ventilation, dry, humidity below 60%, and temperature \leq 40 °C. Cells should be sampling inspected again if the storage time over 45 days.